Important Note: 1. On completing your answers, compulsorily draw diagonal cross lines on the remaining blank pages. 2. Any revealing of identification, appeal to evaluator and /or equations written eg. 42+8 = 50, will be treated as malpractice.

USN

First/Second Semester B.E. Degree Examination, June/July 2014

Basic Electronics

Time: 3 hrs.	Max. Marks: 100

Note: 1. Answer any FIVE full questions, choosing at least two from each part.

2. Answer all objective type questions only in OMR sheet page 5 of the answer booklet.

	3	. Ans	swer to objective	type questions on s	sheets other than OMR	will not be valued.	
				PAR	$\Gamma - \mathbf{A}$		
1	a.	Cho	ose the correct ar	swers for the follow		(04 Marks)	
		i)	Zener diode can be used for rectification. This statement is				
			A) true		B) false	·	
			C) neither true	nor false	D) none of thes	se .	
		ii)			re rectifier is		
		ŕ	A) 40.6%	B) 60.4%	C) 78.5%	D) 81.2%	
		iii)	The knee voltage	e of a silicon diode i	is .	2) 01.2/0	
			A) 0.3V	e of a silicon diode i B) 0.5V	C) 0.7V	D) none of these	
		iv)	If f Hz is the fre	quency of the input	given to a half wave rec	tifier, the output frequency	
			will be		6	medicine surput nequency	
			A) 2f Hz	B) f Hz	C) 3f Hz	D) 0.5f Hz	
	b. c.	With	n a neat circuit dia	VI – characteristics of agram, explain the work of the ctor = 0.48, and efficient of the ctor = 0.48.	of a Si-diode and Ge-dio orking principles of full ciency = 81.2%.	ode. (06 Marks) I wave bridge rectifier and (10 Marks)	
2	a.		ose the correct an	(04 Marks)			
		i)	The current con-				
			A) electrons		B) holes		
			C) both electron	s and holes	D) none of thes	e	
		ii)	If $\alpha = 0.95$, then				
			A) 0.05	B) 19	C) 100	D) 120	
		iii)	Common collect				
				natching		lification	
			C) current ampli		_ /		
		iv)	iv) The current relationship between two current gain in a transistor is				

A)
$$\beta = \frac{\alpha}{1-\alpha}$$

B)
$$\beta = \frac{1+\alpha}{1-\alpha}$$

C)
$$\beta = \frac{1-\alpha}{1+\alpha}$$

D)
$$\beta = \frac{1+\beta}{\beta}$$

- b. Draw input and output characteristics of an NPN transistor in common base configuration (10 Marks)
- For a Silicon transistor α_{dc} = 0.995, emitter current is 10 mA and leakage current I_{co} is $0.5\mu A$. Find I_C , I_B , β and I_{CEO} . (06 Marks)

3	a.	Cho	ose the correct answer			(04 Marks)		
		i)	Which of the following	ng factor affects the Q	-point stability?			
			A) I_{co}		B) coupling capacito	r		
			C) emitter resistor		D) bypass capacitor			
		ii)		he do load line with gi	ven base current curve	is the		
		/	A) h-point	B) D-point		D) none of these		
		iii)		er, the voltage gain is	c) Q point	D) none of these		
		111)	A) unity	R) greater than unity	C) less than unity	D) zoro		
		iv)	,					
		10)			ing biasing met C) voltage divider			
			A) fixed	b) conector to base	c) voltage divider	D) none of these		
	b.	Explain the working of collector-to-base bias circuit using an NPN transistor and derive the						
		equation for I_B . (08 Marks						
	c.	Defi	Define stability factor and discuss the factors that cause instability of biasing circuits.					
			•		·	(08 Marks)		
4	a.	Cho	ose the correct answers	•		(04 Marks)		
		i)	FET is a co	ntrolled device.				
			A) voltage		C) pulse	D) power		
		ii)	PNPN device is an _	•				
			A) UJT	B) SCR	C) MOSFET	D) MODFET		
		iii)	used as a re					
			A) MOSFET		C) BJT	D) UJT		
		iv)		f ratio of UJT				
			A) equal to one		B) must be less than	unity		
			C) must be greater th	an unity	D) must be zero			
	b.	. Explain the working of two transistor model of an SCR and obtain the expression for the						
		anode current. (08 Ma						
	c. Draw the equivalent circuit and VI-characteristic of UJT and explain it.							
				PART - B				
5	a.	Cho	ose the correct answers			(04 Marks)		
			Oscillator uses			(**************************************		
			A) positive	B) negative	C) reverse	D) both A and B		
		ii)	•	illations in an oscillate	,			
						1		
			A) $\frac{1}{2\pi LC}$	B) 2πLC	C) $2\pi\sqrt{LC}$	D) $\frac{1}{2\pi\sqrt{LC}}$		
		iii)	With negative feedba	ick, the bandwidth of a		,		
		,	A) decreases	B) increases	C) both A and B	D) constant		
		iv)	,	*	frequencies of an RC	,		
		,	times maximun					
			A) 0.707	B) 7.07	C) 10	D) 17.06		
			,		0,10	2)		
	b.	Draw the frequency response of an RC-coupled amplifier and explain it. Mention its						
	-	advantages and disadvantages. (08 Marl						
	c.							
	transistor.					(06 Marks)		
	d.	$c_1 = 0.001 \mu F$ and						
	u.		_	-	-	•		
		c_2	$0.01 \mu F \text{ if L} = 5 \mu H, ca$	neurate the nequency (or oscillations.	(02 Marks)		

6	a.	Cho	ose the correct answe	ers for the following:		(04 Marks)		
		i)	The gain of the volt	age follower is	•	(,		
			A) zero	B) infinite	C) negative	D) unity		
		ii)	Ideally open loop ga	ain of op-amp is	,	, ,		
			A) 0	B) 1		D) positive		
		iii)	The CMRR is given	a by	•	, ,		
			A) $A_d \times A_c$	B) A_c/A_d	C) A_d/A_c	D) none of these		
		iv)	Maximum rate of cl	nange of output voltage	e with time is called			
			A) CMRR	B) slew rate	C) over rate	D) none of these		
	b.	List the characteristics of an ideal-op-amp and draw the three input inverting summer circuit						
		using an op-amp and derive an expression for output voltage.						
	c.	Drav	w the basic block diag	ram of a cathode ray to	ube and explain its work	(08 Marks) king. (08 Marks)		
			_	•	,	(**************************************		
_		CI						
7	a.		ose the correct answe	rs for the following:		(04 Marks)		
		i)	Two's compliant of	(1001) ₂ is				
		::5	A) 1001		C) 0111	D) 1010		
		ii)	10 represent 35 in b	inary, number of bits r	required is			
		iii)	A) 6	B) 5	C) 4	D) 33		
		111)	A) 100111	is represented in BCD	C) 00110111	D) 111100		
		iv)	Over modulation av	B) 00111011	C) 00110111	D) 111100		
		14,	A) 1	ists when modulation i B) 0	C) >1	D) < 1		
			, .	<i>D</i>) 0	C) ~1	D) < 1		
	b.	Expl	ain the need for modu	ılation.		(06 Marks)		
	c.			$_{0}$, and $(247.75)_{10} = ($)2.	(04 Marks)		
	d.	i) Perform (FC02A) ₁₆ – (D052) ₁₆ using 16's complement.						
		ii) Subtract (4217 64) 6 (42 246) 1 01						
					•	(06 Marks)		
8	a.	Cho	ose the correct answer	rs for the following:		(04 Marks)		
		i)	The expression for h	alf adder carry with in	put A and B is given by			
			A) $A + B$	B) AB	C) \overline{A} \overline{B}	D) none of these		
		ii)	The complement of	A + B + 1 is	,	-)		
			A) 0	B) A + 1	C) AB + 1	D) 1		
		iii)	ABCD + ABD is equ	ual to	·	,		
			A) ABC	B) \overline{ABC}	C) ABD	D) ABD		
		iv)	A + (B + C) = (A +		•	D) HBD		
			A) associative		C) distributive	D) none of these		
	,	_				,		
	b.	Design a full adder circuit and realize, using two half adders. (08 Marks)						
	C.	Simp	Simplify the following expressions and implement using only NAND gates:					
		i) Y	$= ABC + A\overline{B}C + AB\overline{C}$	$\overline{C} + \overline{ABC}$	•			
ii) $Y = \overline{\overline{AB} + \overline{AC}}$								
			$= A + \overline{AB}$.					
		, 1	- A + AD,			(08 Marks)		

* * * * *

